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Published in:
Advanced Science

DOI:
10.1002/advs.202204683

Published: 03/02/2023

Document Version
Publisher's PDF, also known as Version of record

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Please cite the original version:
Energy Efficient Single Pulse Switching of [Co/Gd/Pt]$_N$ Nanodisks Using Surface Lattice Resonances

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The impact of plasmonic surface lattice resonances on the magneto-optical properties and energy absorption efficiency has been studied in arrays of [Co/Gd/Pt]$_N$ multilayer nanodisks. Varying the light wavelength, the disk diameter, and the period of the array, it is demonstrated that surface lattice resonances allow all-optical single pulse switching of [Co/Gd/Pt]$_N$ nanodisk arrays with an energy 400% smaller than the energy needed to switch a continuous [Co/Gd/Pt]$_N$ film. Moreover, the magneto-optical Faraday effect is enhanced at the resonance condition by up to 5,000%. The influence of the disk diameter and array period on the amplitude, width and position of the surface lattice resonances is in qualitative agreement with theoretical calculations and opens the way to designing magnetic metasurfaces for all-optical magnetization switching applications.

1. Introduction

All-optical magnetization manipulation using ultrashort laser pulses and its potential applicability fits with the ceaseless demand for ultrafast and energy efficient magnetic recording.[1–17] Single pulse all-optical helicity-independent switching (AO-HIS) has been demonstrated first in GdFeCo alloys in 2011.[18] AO-HIS is believed to be a thermal effect that induces the demagnetization of the Gd and FeCo sublattices whose demagnetization timescales are different and allow exchange of angular momentum between Gd and FeCo leading to toggle switching.[19] Compared to hard-disk drives on the market, the writing speed of AO-HIS in ferrimagnetic rare-earth transition-metal (RE-TM) alloys is ≈ 10 times faster with a full magnetization switching time around hundreds of ps.[18] Recently, it has been reported that single pulse AO-HIS is also achievable in Co/Gd multilayers[18] with timescales comparable to the corresponding RE-TM alloys.[19] This system is of particular interest because the AO-HIS can be achieved without any composition requirements[18,20] in opposite to GdFeCo alloys or Tb/Co multilayers,[21] facilitating the production on wafers. The fluence needed to switch magnetization with one single laser pulse is much lower than the other systems showing AO-HIS.[17,18] Moreover this synthetic-ferrimagnetic multilayer fits the demands of the data storage industry as it can overcome thermal annealing[22] required for fabricating nanostructures or opto-controllable magnetic tunnel junctions.[23,24]

In future applications, AO-HIS is needed to achieve ultrafast magnetic recording while increasing current all-optical areal recording densities requires nanostructures whose writing resolution is not limited by the diffraction limit. Plasmonics provide the tools to manipulate light beyond the diffraction limit.[25] In 2015, Liu et al. exploited two-wire plasmonic gold nanoantennas on a TbFeCo film to induce all-optical switching in an area whose lateral size is 53 nm with a threshold fluence reduction of 37% thanks to field enhancement in the near field.[13] Moreover Kataja et al. showed in 2018 that demagnetization and field-assisted magnetization switching in periodic magnetic nanoparticles are improved at the surface lattice resonance (SLR) wavelength due to the enhanced nanoparticle absorption facilitated by these modes.[26]

In this paper, we study plasmon-assisted femtosecond laser-induced single pulse AO-HIS and the magneto-optical response of [Co/Gd/Pt]$_N$ nanodisk arrays. The effect of the disk diameter, the array period and the light wavelength on optical switching and the magneto-optical response are determined. We
We measured the hysteresis loops of the [Co/Gd/Pt]N nanodisk arrays and the unpatterned [Co/Gd/Pt]N film with N = 1, 2, 3, 4, 5, and 6 using the polar magneto-optical Faraday and Kerr effect, respectively (see Figure S4, Supporting Information). The coercive field of the films ranges from 9.5 to 3.2 mT for N = 1, 2, 3, and 4. For N > 4, the remanence decreases significantly because of domain formation (see Figure S4, Supporting Information). From MFM images and the domain size in [Co/Gd/Pt]N = 5, 6 continuous films, we deduce that the [Co/Gd/Pt]N = 5, 6 nanodisks are still single domain. Besides, the perpendicular magnetization of [Co/Gd/Pt]N metasurfaces reverses abruptly in an applied magnetic field for any N. Magnetic switching in the [Co/Gd/Pt]N nanodisks requires larger magnetic field than the unpatterned film due to the lower probability of domain nucleation within the disks.

We focused on N = 2 for studying the impact of plasmon excitations on single pulse AO-HIS as a good compromise between strong magneto-optical signal and achievable toggle switching in the continuous film at any wavelength of interest for AO-HIS. Experiments with linearly polarized light, along one of the primary axes of the nanodisk arrays, were conducted at wavelengths ranging from 650 to 1000 nm. The AOS experiments were conducted using 216 fs laser pulses from a Yt fiber laser with regenerative amplifier (see Figure S3, Supporting Information). Images of magnetization switching obtained on the [Co/Gd/Pt]N film and a [Co/Gd/Pt]2 metasurface with D = 150 nm and P = 500 nm are presented in Figure 2 for different laser fluences and for a wavelength of 650 and 825 nm. By comparing the size of the switched area and the fluence needed to achieve AO-HIS, it is obvious that the metasurface switches at considerably smaller energy than the unpatterned film. While more efficient AO-HIS is attained in the metasurface at both wavelengths, the effect is particularly strong for 825 nm, where the laser fluence is reduced by a factor 4. The wavelength dependence of single-pulse AO-HIS in metasurfaces with D = 150, 200, and 250 nm and P = 500 nm and the unpatterned film is summarized in Figure 3a (see Figure S5, Supporting Information, for P = 550 nm). Here, we plot the ratio of the laser threshold fluence needed to induce optical switching in the film and metasurface \((F_{th - film}/F_{th - array})\). At almost all wavelengths, single-pulse AO-HIS is more efficient in the metasurfaces than the unpatterned film and the condition of optimal switching efficiency shifts to larger wavelength with increasing nanodisk diameter.

The improved energy efficiency of AO-HIS in the metasurfaces is explained by the excitation of a collective SLR, as suggested by the optical extinction curves shown in Figure 3b. The extinction spectra are shaped by the diffracted order (DO) of the nanodisk array (sharp minimum at \(\approx 760\) nm) and a broader SLR (maximum following the DO) resulting from hybridization between the DO and the local surface plasmon resonance of individual nanodisks.\(^{28-31}\) Since the SLR mode absorbs light more than it scatters\(^{32,33}\) the extinction spectra are a good measure of light absorption by the [Co/Gd/Pt]N metasurfaces (see Figure S6, Supporting Information, for spectra of other metasurfaces with different N). As AO-HIS is driven by a pure thermal effect, strong optical absorption by the SLR explains the improved energy efficiency of AO-HIS in the metasurfaces. To corroborate that stronger optical absorption per unit area explains the gain in switching efficiency, we scaled the extinction spectra of the
metasurfaces with their filling factor (area covered by the nanodisks divided by the total area) and normalized the result to the extinction recorded on the continuous film (Figure 3b). Clearly the shapes of the normalized extinction curves closely resemble the threshold fluence data shown in Figure 3a. This correspondence provides a powerful tool for minimizing the AO-HIS energy in magnetoplasmonic systems through straightforward extinction measurements using a continuous laser. Finite element method (FEM) simulations of the normalized extinction (Figure 3a) support the experimental findings. For the metasurfaces discussed here (P = 500 nm), most efficient AO-HIS is attained for the metasurface with D = 150 nm because of the strongest optical absorption per unit area, as further confirmed by the simulated intensity of the optical near fields shown in Figure 3d–f (see Figure S7, Supporting Information, for the optical constants).

To further support the conclusions on AO-HIS, we performed repetitive switching measurements on the continuous films and metasurfaces. While the films show 100% repetitive single pulse AO-HIS (see Figure S8, Supporting Information), the switching rates are smaller for the corresponding metasurfaces. For instance, Figure 4a depicts 8 MOKE images recorded following repetitive switching by eight successive laser pulses for D = 150 nm, P = 500 nm, and laser fluence F = 1.26 mJ cm$^{-2}$. The switching rate, defined as $m = M_M / M_0$ decreases when the disk diameter increases (see Figure S8, Supporting Information), reaching 88% for D = 150 nm, 76% for D = 200 nm, and 66% for D = 250 nm. In particular, we notice that the switching rate after X pulses can be written as

$$m_X = \prod_i m_i \quad \text{with} \quad \sum_i i = X$$

as confirmed by Figure 4b showing the normalized radial switching rate profiles after 8 successive laser pulses. Then Figure 4c plots the switching rate at the center of the metasurface as a function of laser pulse number illuminating the metasurface. We conclude from Figure 4 and Figure S8 (Supporting Information) that the switching rate increases when the disk size decreases, paving the path to reach 100% repetitive switching for magnetic bits even smaller than 150 nm.

The data presented thus far demonstrate how SLR excitations can significantly aid the writing process in all-optical magnetic recording. Magneto-optical readout of stored information is another key requirement of this data storage technology. To assess the effect of collective SLRs on the magneto-optical read-out...
matches the lattice factor of the periodic array.\[35,38\] To quantify the Faraday angles of the [Co/Gd/Pt]N metasurfaces and of the magneto-optical readout sensitivity, we extracted the ratio of the inverse polarizability of the individual [Co/Gd/Pt]N nanodisks by a resonant enhancement of the magneto-optical activity when $D_\text{am}$ is minimal at the DO $P = 500 \text{ nm}$. The laser fluence is $1.26 \text{ mJ/cm}^2$ and the wavelength is at 650 nm. b) Corresponding switching rate profiles across the switching areas after each single-pulse switching experiment. c) Switching rate at the center of the metasurface as a function of the number of pulses. The scale bar indicates 50 $\mu\text{m}$.

Figure 4. a) MOKE images after each single pulse switching for a [Co/Gd/Pt]$_N$ metasurface with $D = 150 \text{ nm}$ and $P = 500 \text{ nm}$. The laser fluence is 1.26 mJ cm$^{-2}$ and the wavelength is at 650 nm. b) Corresponding switching rate profiles across the switching areas after each single-pulse switching experiment. c) Switching rate at the center of the metasurface as a function of the number of pulses. The scale bar indicates 50 $\mu\text{m}$.

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<th>$D_\text{am}$ (nm)</th>
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Figure 5. Faraday readout sensitivity. a) Faraday angle spectrum for a [Co/Gd/Pt]$_N$ multilayer with $D = 150 \text{ nm}$ and $P = 500 \text{ nm}$. b) Ratio of the Faraday angles measured on the [Co/Gd/Pt]$_2$ metasurfaces and the [Co/Gd/Pt]$_N$ continuous films at the SLR wavelength, scaled to the filling factors of the nanodisk arrays.

Another parameter that is essential for magneto-optical readout is the signal-to-noise ratio (SNR), which relates to the magneto-optical contrast at the readout wavelength. Indeed, we had to optimize this quantity when performing ultrafast measurements in a reflection configuration (see Figure S3, Supporting Information) as all the statements about AO-HIS are based on images analysis. To quantify the SNR, we define the magneto-optical contrast as

$$C = \frac{\Delta I}{\Sigma I} = \frac{I_{0+} - I_{0-}}{I_{0+} + I_{0-}}$$

where $I_{0+}$ ($I_{0-}$) is the light intensity probed for magnetization pointing up (down). $\Delta$ and $\Sigma I$ are linked to the Kerr rotation $\theta$ and ellipticity $\eta$ so that the contrast can be rewritten as

$$C = \frac{\sin(2\alpha) \times \theta}{\sin(\alpha) + (\theta^2 + \eta^2) \times \cos(\alpha)}$$

where $\alpha$ is the angle between the polarizer and the analyzer. Modulation of the Kerr rotation and ellipticity by the excitation of a SLR provides accurate tuning of the wavelength at which the SNR is maximized. Figure 6 depicts how the magneto-optical contrast shifts when the array period is changed for a metasurface with $D = 150 \text{ nm}$ (see Figure S11, Supporting Information).

3. Conclusion

In summary, we demonstrated energy-efficient plasmon-assisted magnetization switching and sensitive magneto-optical readout in perpendicularly magnetized metasurfaces comprising periodic arrays of [Co/Gd/Pt]$_N$ nanodisks. Both the single-pulse optical writing and magneto-optical readout are significantly enhanced by the excitation of collective SLRs. The laser threshold fluence for magnetization switching and the magneto-optical response of the metasurfaces can be accurately tuned by the disk diameter and array period providing a versatile design strategy towards the realization of energy-efficient plasmon assisted magnetic recording technologies.

4. Experimental Section

Film Growth: The Pt(1)/Pt(3)/Gd(2)/Co(1)/Pt(5)/Ta(5) multilayer stack was grown on a glass substrate by magnetron sputtering in a PVD-8 system from Vinci Technologies. The Ar deposition pressure was set to $5 \times 10^{-8} \text{ Torr}$ and all layers were grown at room temperature.

Metasurface Fabrication: The [Co/Gd/Pt]$_N$ multilayer stacks were patterned from the continuous multilayer stack using e-beam lithography in a...
RAITH 150–2 system. In the lithography process, a 50 nm thick Al etching mask was first defined using a lift-off process. Hereafter, ion beam etching (IBE) was used at an optimized angle of 10°. The mask was first defined using a lift-off process. Ion Beam Etching (IBE) was used at an optimized angle of 10°. The sample with linearly polarized light was illuminated and the change of polarization was probed upon reflection from the sample to obtain the complex reflectance ratio \( r_p/r_s \). Optical constants were extracted from the ellipsometry measurements using CompleteEASE software and assuming a single layer system. The CompleteEASE software utilizes a Bruggeman effective medium approach to minimize the mean-square deviation between measured and calculated ellipsometry parameters. The extracted effective refractive index was used in COMSOL simulations to calculate transmission (1 – extinction) and reflection spectra as well as the distribution of optical near-fields.

**Supporting Information**

Supporting Information is available from the Wiley Online Library or from the author.

**Acknowledgements**

Maxime Vergès was supported by a CIFRE Ph.D. grant from Vinci Technologies. This work was supported by the ANR-20-CE09-0013 UFO, by the Institut Carnot ICELL for the project “CAPMAT” and FASTNESS, by the Région Grand Est, by the Metropole Grand Nancy, for the Chaire PLUS by the impact project LUE-N4S, part of the French PIA project “Lorraine Université d’Excellence” reference ANR-15-IDEX-04-LUE, by the “FEDERFSE Lorraine et Massif Vosges 2014–2020”, a European Union Program, and by the Academy of Finland (grant no. 316857). The devices in the present study were patterned at MiNaLor platform that is partially funded by Grand Est Region and Feder through RANGE project.

**Conflict of Interest**

The authors declare no conflict of interest.

**Author Contributions**

M.V., S.P., J.H., S.V.-D., and S.M. planned the study. M.H. grew the multilayer stack. M.V. fabricated the metasurfaces by e-beam lithography and conducted scanning electron microscopy measurements. S.P. and Y.L.-G. performed the optical transmission and magneto-optical measurements. M.V. and J.H. conducted AOS experiments and Y.L.-G. assisted the measurements. M.V., S.P., and Y.L.-G. analyzed the optical, magneto-optical and AOS data with input from other authors. M.V. performed the FEM simulations. M.V., J.H., S.V.-D., and S.M. wrote the manuscript with input from other authors. M.V. conducted AOS experiments and Y.L.-G. assisted the measurements. S.P. and Y.L.-G. conducted scanning electron microscopy measurements. S.P. and Y.L.-G. analyzed the optical, magneto-optical and AOS data with input from other authors. M.V. performed the FEM simulations. M.V., J.H., S.V.-D., and S.M. wrote the manuscript with input from other authors. All authors discussed the results.

**Data Availability Statement**

The data that support the findings of this study are available from the corresponding author upon reasonable request.

**Keywords**

all-optical magnetization switching, plasmonics, surface lattice resonance, ultrafast physics